

P-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY			
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^c	Q _g (Typ.)
- 20	0.66 at V _{GS} = - 4.5 V	- 0.8	0.75 nC
	1.60 at V _{GS} = - 2.5 V	- 0.55	

FEATURES

- DT-Trench Power MOSFET
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC
- Gate-Source ESD Protected

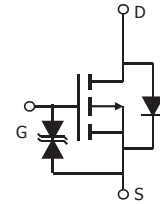
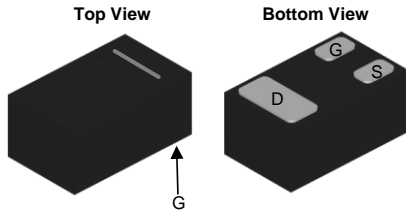


RoHS
COMPLIANT

APPLICATIONS

- Load Switch

DFN 1006



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)				
Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	- 20	V
Gate-Source Voltage		V _{GS}	± 12	
Continuous Drain Current (T _J = 150 °C)	T _C = 25 °C	I _D	- 0.8	A
	T _C = 70 °C		- 0.5	
	T _A = 25 °C		- 0.3 ^{a, b}	
	T _A = 70 °C		- 0.15 ^{a, b}	
Pulsed Drain Current		I _{DM}	- 3	
Continuous Source-Drain Diode Current	T _C = 25 °C	I _S	- 0.8	
	T _A = 25 °C		- 0.3	
Maximum Power Dissipation	T _C = 25 °C	P _D	0.95	W
	T _C = 70 °C		0.61	
	T _A = 25 °C		0.3 ^{a, b}	
	T _A = 70 °C		0.19 ^{a, b}	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 50 to 150	°C
Soldering Recommendations (Peak Temperature)			260	

Notes:

a. Surface mounted on 1" x 1" FR4 board.

b. t = 10 s.

c. Based on T_C = 25 °C.

THERMAL RESISTANCE RATINGS

Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^{a, b}	$t \leq 10$ s	R_{thJA}	250	500	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	225	670	

Notes:

- a. Surface mounted on 1" x 1" FR4 board.
 b. Maximum under steady state conditions is 360 °C/W.

SPECIFICATIONS ($T_J = 25$ °C, unless otherwise noted)

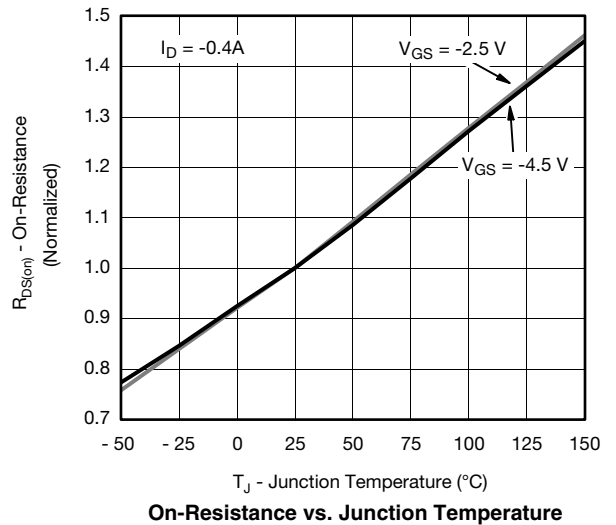
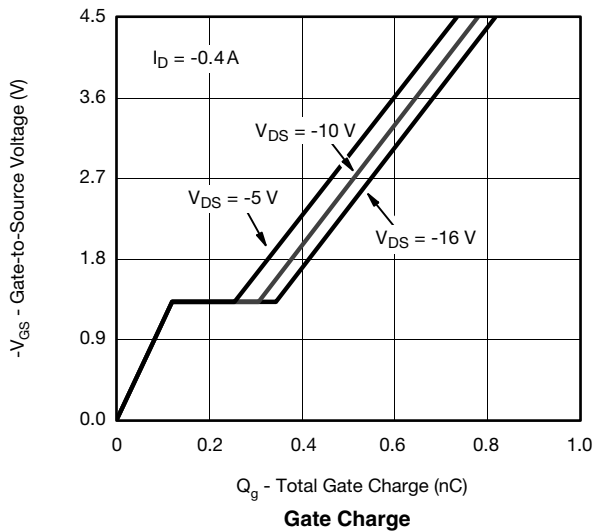
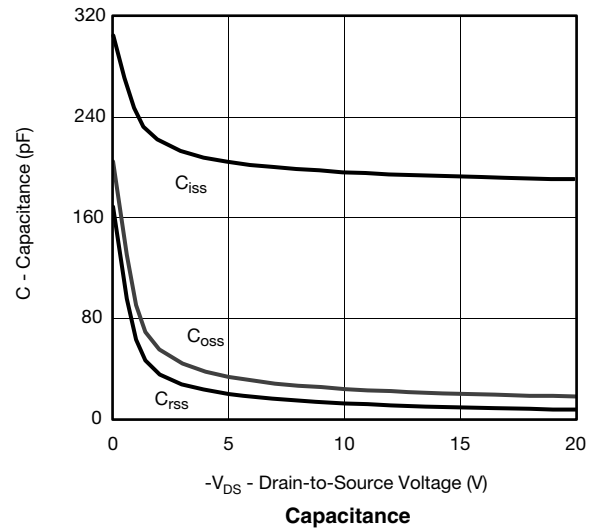
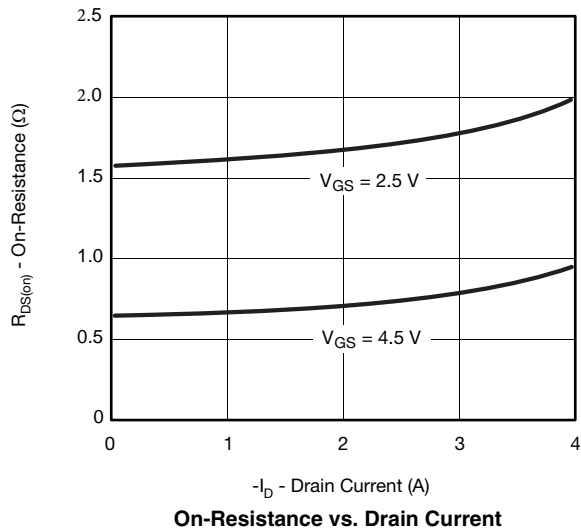
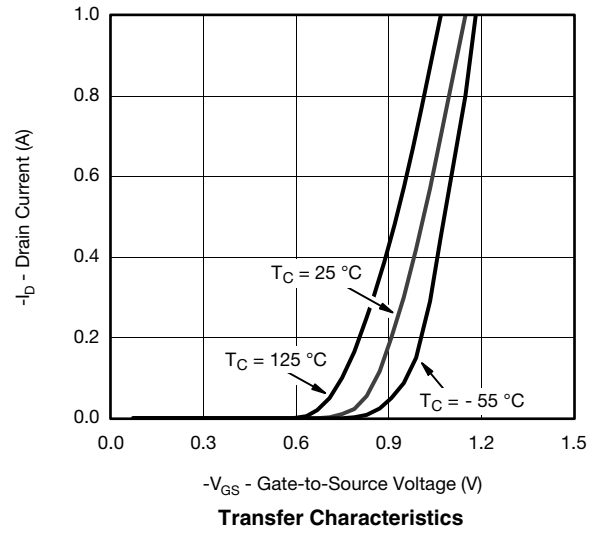
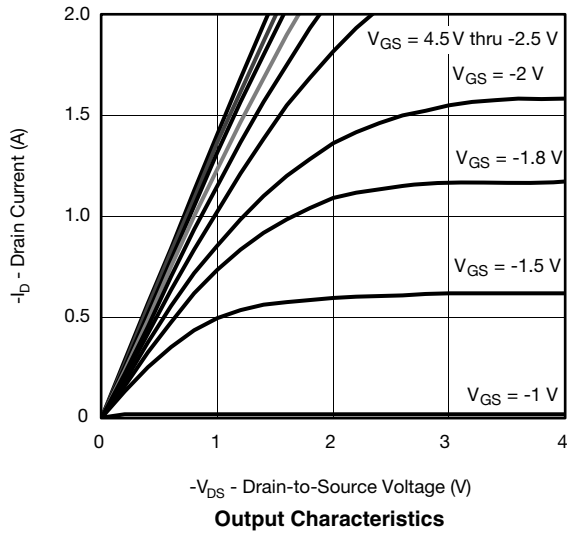
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0$ V, $I_D = -250$ μ A	- 20			V
V_{DS} Temperature Coefficient	$\Delta V_{DS}/T_J$	$I_D = -250$ μ A		- 14		mV/°C
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$		2.4			
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -250$ μ A	- 0.4		- 1.0	V
Gate-Source Leakage	I_{GSS}	$V_{DS} = 0$ V, $V_{GS} = \pm 12$ V			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -20$ V, $V_{GS} = 0$ V			- 1	μ A
		$V_{DS} = -20$ V, $V_{GS} = 0$ V, $T_J = 55$ °C			- 10	
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} \leq -5$ V, $V_{GS} = -4.5$ V	- 0.8			A
Drain-Source On-State Resistance ^a	$R_{DS(on)}$	$V_{GS} = -4.5$ V, $I_D = -0.4$ A		0.66	0.85	Ω
		$V_{GS} = -2.5$ V, $I_D = -0.2$ A		1.60	2.0	
Forward Transconductance ^a	g_{fs}	$V_{DS} = -5$ V, $I_D = -0.4$ A		1		S
Dynamic^b						
Input Capacitance	C_{iss}	$V_{DS} = -10$ V, $V_{GS} = 0$ V, $f = 1$ MHz		192		pF
Output Capacitance	C_{oss}		27			
Reverse Transfer Capacitance	C_{rss}		14			
Total Gate Charge	Q_g	$V_{DS} = -10$ V, $V_{GS} = -4.5$ V, $I_D = -0.4$ A		0.75		nC
Gate-Source Charge	Q_{gs}		0.2			
Gate-Drain Charge	Q_{gd}		0.3			
Gate Resistance	R_g	$f = 1$ MHz		43		Ω
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -10$ V, $R_L = 9.1$ Ω $I_D \cong -0.4$ A, $V_{GEN} = -4.5$ V, $R_g = 1$ Ω		12		ns
Rise Time	t_r		8			
Turn-Off DelayTime	$t_{d(off)}$		23			
Fall Time	t_f		9			
Drain-Source Body Diode Characteristics						
Continuous Source-Drain Diode Current	I_S	$T_C = 25$ °C			- 0.8	A
Pulse Diode Forward Current ^a	I_{SM}				- 3	
Body Diode Voltage	V_{SD}	$I_F = -0.7$ A		- 0.8	- 1.2	V
Body Diode Reverse Recovery Time	t_{rr}	$I_F = -0.7$ A, $di/dt = 100$ A/ μ s, $T_J = 25$ °C		18		ns
Body Diode Reverse Recovery Charge	Q_{rr}		7		nC	
Reverse Recovery Fall Time	t_a		7		ns	
Reverse Recovery Rise Time	t_b		11			

Notes:

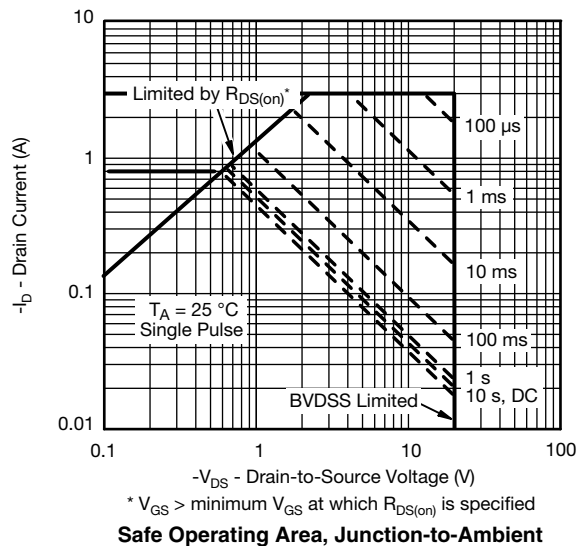
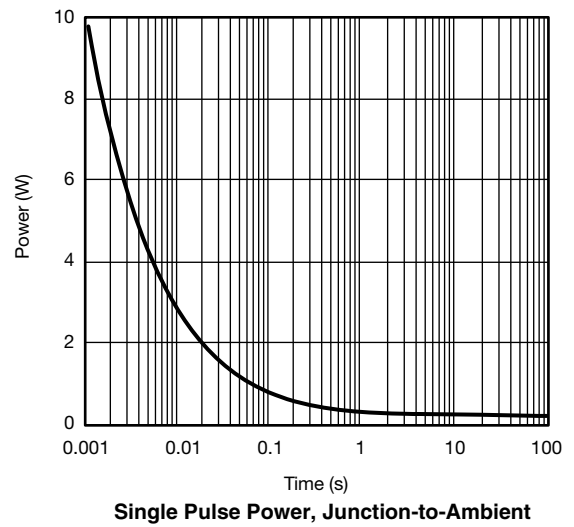
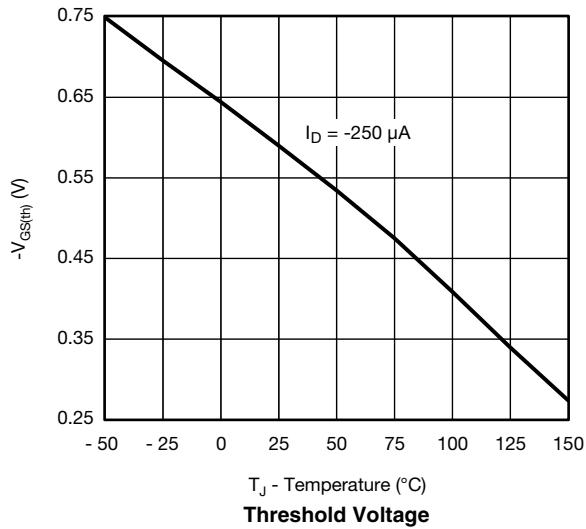
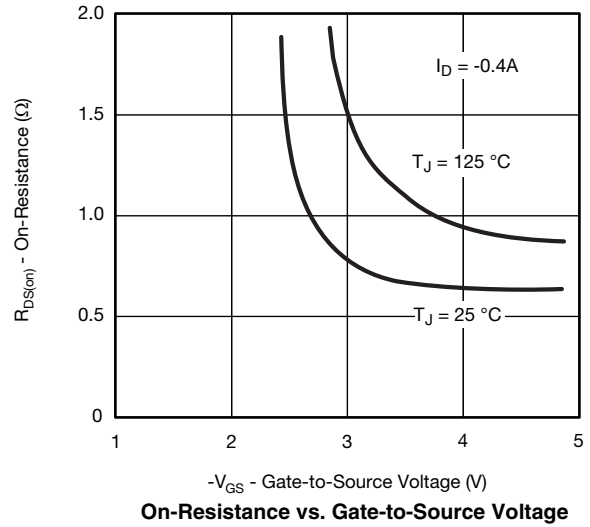
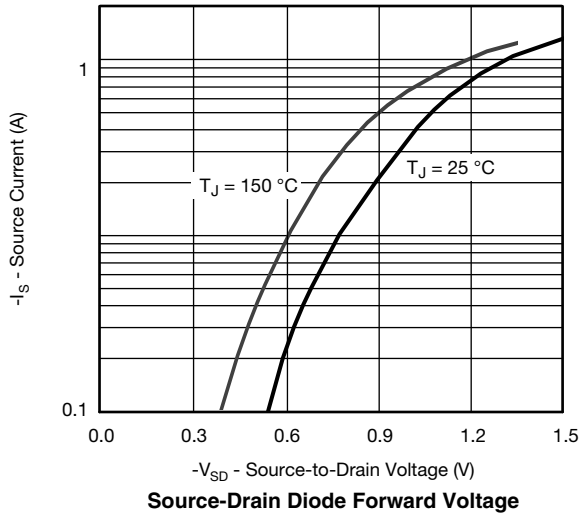
- a. Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %.
 b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

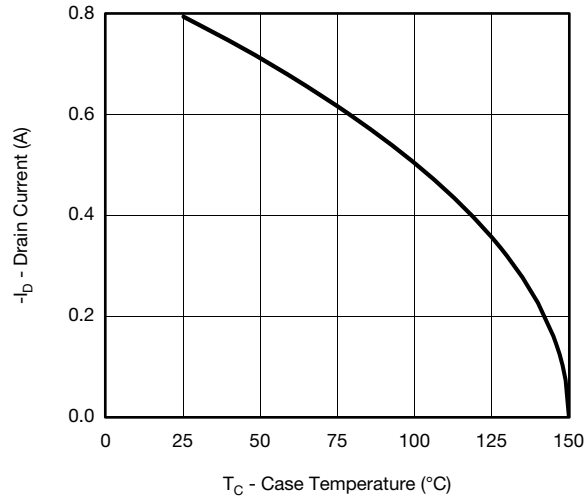
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



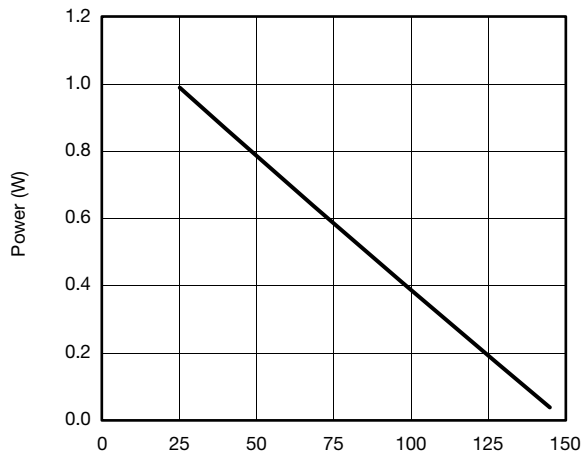
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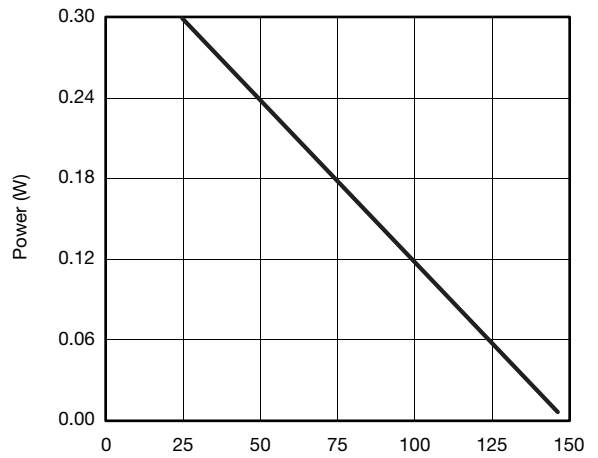
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating*



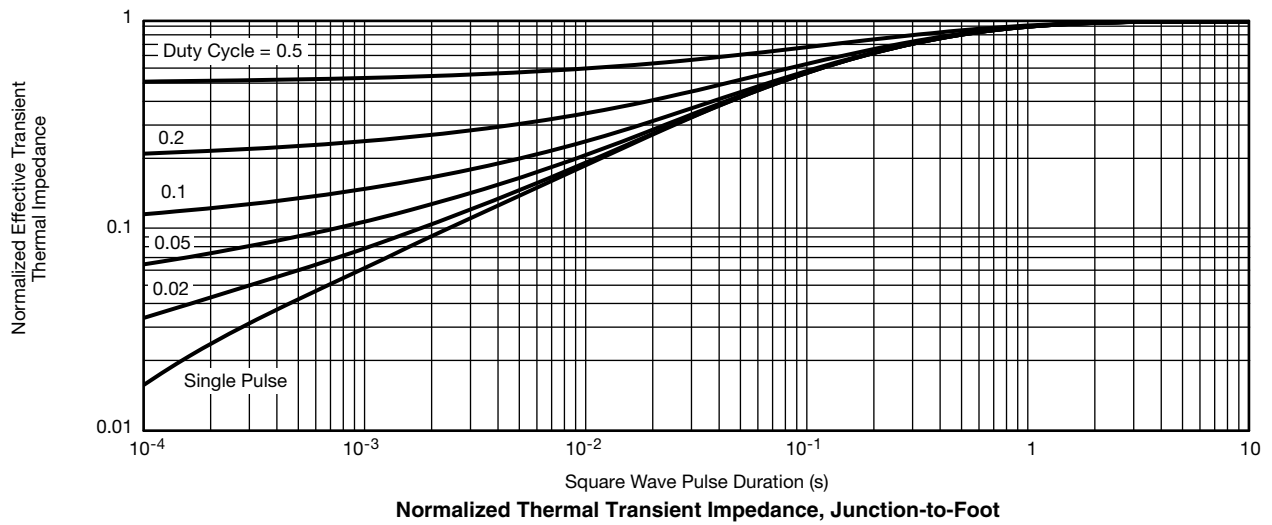
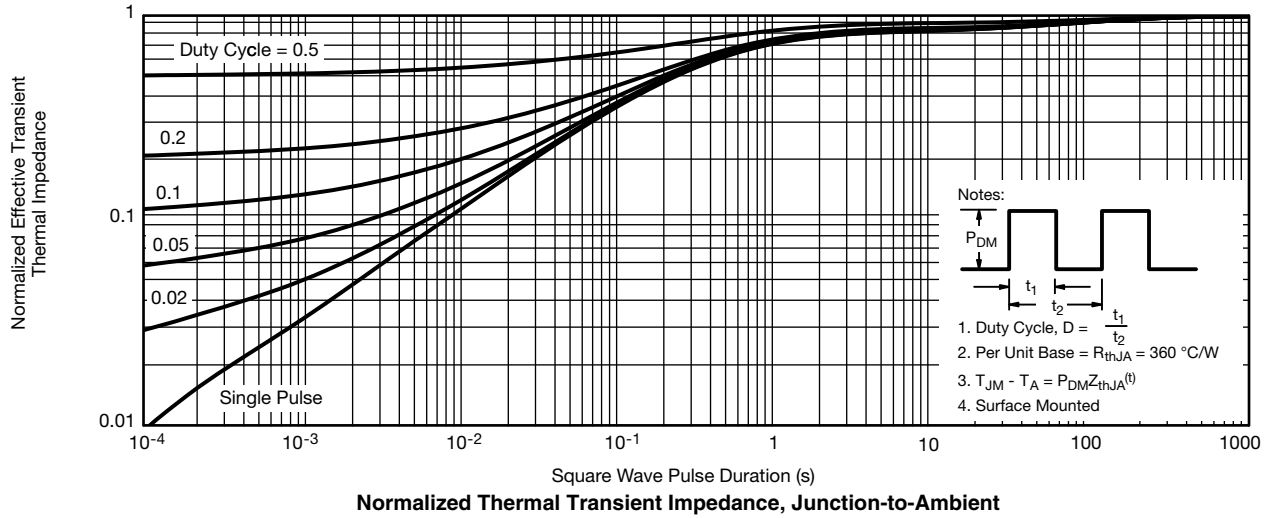
Power, Junction-to-Case



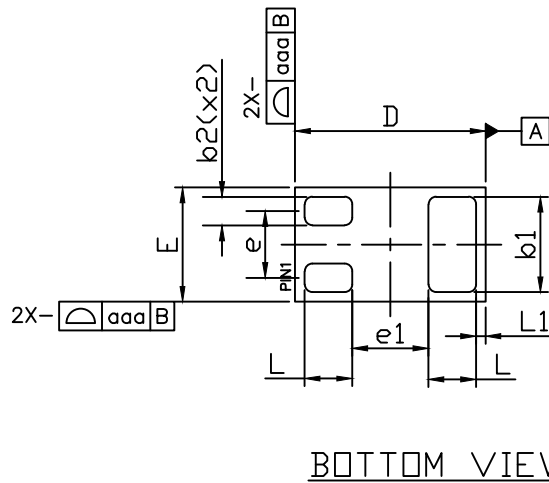
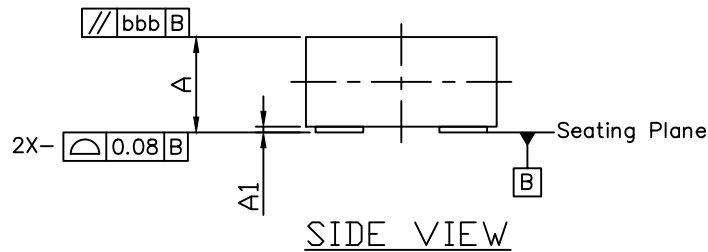
Power, Junction-to-Ambient

* The power dissipation P_D is based on $T_{J(max)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

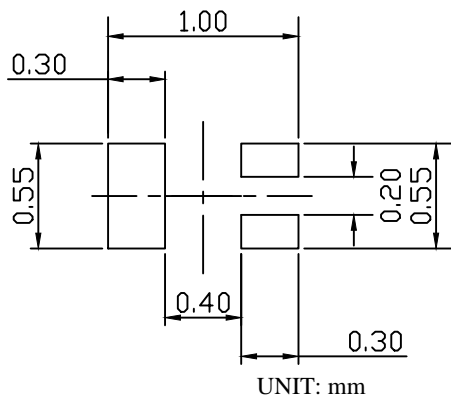
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



DFN1.0x0.6_3L_EP1_S PACKAGE OUTLINE



RECOMMENDED LAND PATTERN



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.47	0.52	0.55	0.019	0.020	0.022
A1	0.00	0.03	0.05	0.000	0.001	0.002
b1	0.45	0.50	0.55	0.018	0.020	0.022
b2	0.10	0.15	0.20	0.004	0.006	0.008
D	0.95	1.00	1.05	0.037	0.039	0.041
E	0.55	0.60	0.65	0.022	0.024	0.026
e	---	0.35	---	---	0.014	---
e1	---	0.40	---	---	0.016	---
L	0.20	0.25	0.30	0.008	0.010	0.012
L1	---	0.05	---	---	0.002	---
aaa	0.15			0.006		
bbb	0.05			0.002		

NOTE

1. ALL DIMENSION ARE IN MILLIMETERS. ANGLES ARE IN DEGREES.
2. COPLANARITY APPLIES TO THE EXPOSED HEAT SINK SLUG AS WELL AS THE TERMINALS.

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